



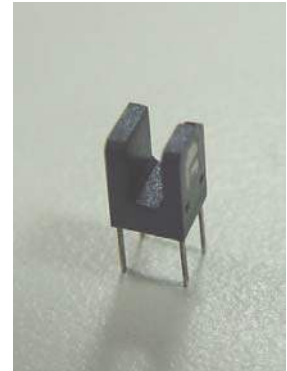
Technical Data Sheet

OPTO INTERRUPTER ITR

ITR9907

■ Features

- Fast response time
- High sensitivity
- Cut-off visible wavelength $\lambda_p=940\text{nm}$
- Thin
- Small package
- Pb free
- The product itself will remain within RoHS compliant version.



■ Descriptions

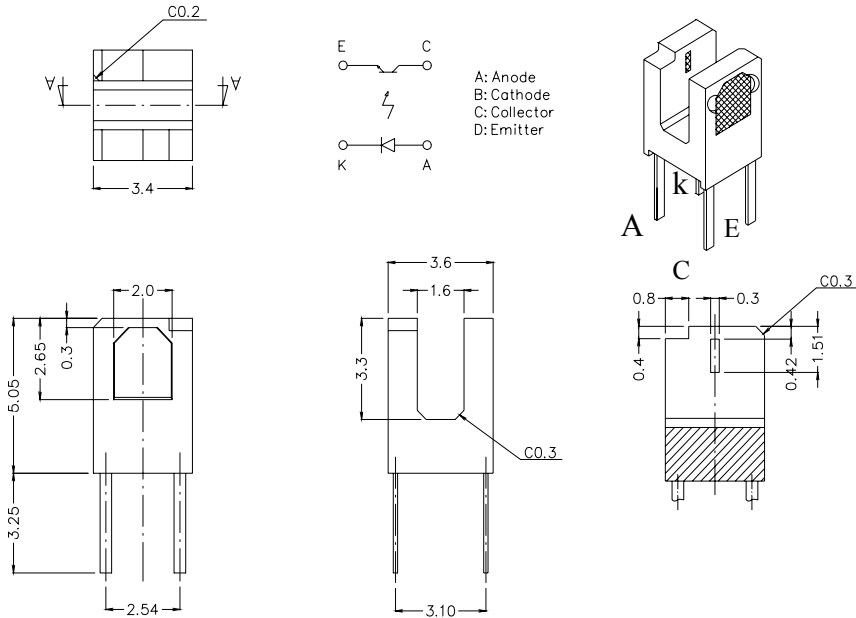
The **ITR9907** consists of an infrared emitting Diode and a silicon phototransistor encased in a black Thermo-plastic housing. The advantage of the device is the small package. Phototransistor receives radiation from the IRED only, and avoids the noise from ambient light

■ Applications

- Camera
- Copier
- Scanner
- Non-contact Switching
- For Direct PC Board

■ Device Selection Guide

Device No.	Chip Material
IR	GaAs
PT	Silicon

Package Dimensions


- Notes:** 1.All dimensions are in millimeters
 2.Tolerances unless dimensions $\pm 0.25\text{mm}$

Absolute Maximum Ratings (Ta=25°C)

Parameter		Symbol	Ratings	Unit
Input	Power Dissipation at(or below) 25°C Free Air Temperature	Pd	75	mW
	Reverse Voltage	V _R	5	V
	Forward Current	I _F	50	mA
	Peak Forward Current (*1) Pulse width $\leq 100 \mu\text{s}$, Duty cycle=1%	I _{FP}	1	A
Output	Collector Power Dissipation	P _C	75	mW
	Collector Current	I _C	20	mA
	Collector-Emitter Voltage	B V _{CEO}	30	V
	Emitter-Collector Voltage	B V _{ECO}	5	V
Operating Temperature		T _{opr}	-25~+85	°C
Storage Temperature		T _{stg}	-40~+85	°C
Lead Soldering Temperature (*2)		T _{sol}	260	°C

(*1) $t_w=100 \mu\text{sec.}$, $T=10 \text{msec.}$ (*2) $t=5 \text{Sec}$

Electro-Optical Characteristics (Ta=25°C)

Parameter		Symbol	Min.	Typ.	Max.	Unit	Conditions
Input	Forward Voltage	V_F	---	1.2	1.6	V	$I_F=20\text{mA}$
	Reverse Current	I_R	---	---	10	μA	$V_R=5\text{V}$
	Peak Wavelength	λ_P	---	940	---	nm	---
Output	Dark Current	I_{CEO}	---	---	100	nA	$V_{CE}=10\text{V}$
	C-E Saturation Voltage	$V_{CE}(\text{sat})$	---	---	0.4	V	$I_C=2\text{mA}$ $E_e=1\text{mW/cm}^2$
Transfer Characteristics	Collector Current	$I_C(\text{ON})$	50	---	---	μA	$V_{CE}=5\text{V}$, $I_F=5\text{mA}$
	Leakage Current	I_{CEOD}	---	---	1	μA	$V_{CE}=5\text{V}$ $I_F=20\text{mA}$
	Rise time	t_r	---	15	---	μsec	$V_{CE}=2\text{V}$ $I_C=1\text{mA}$ $R_L=1\text{K}\Omega$
	Fall time	t_f	---	15	---	μsec	

Typical Electrical/Optical/Characteristics Curves for IR

Fig.1 Forward Current vs. Ambient Temperature

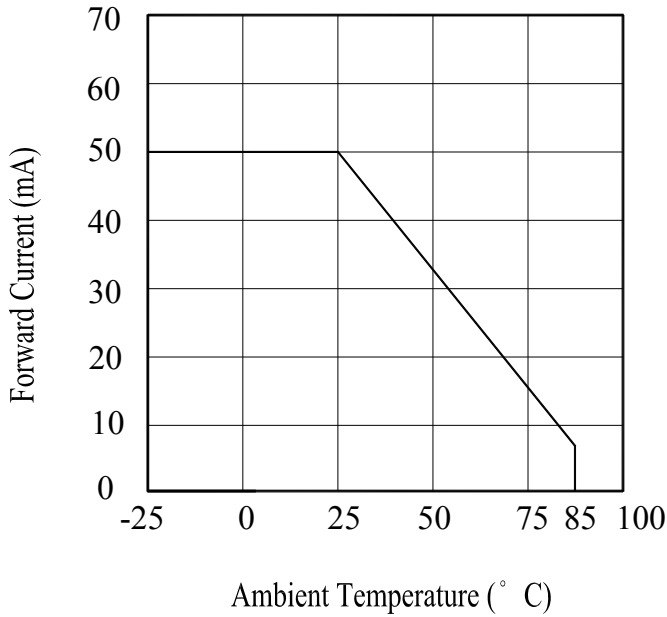


Fig.2 Spectral Distribution

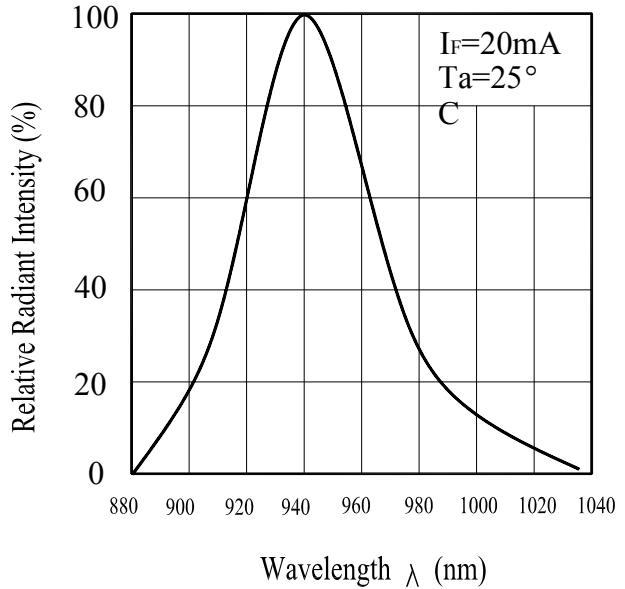


Fig.3 Peak Emission Wavelength vs. Ambient Temperature

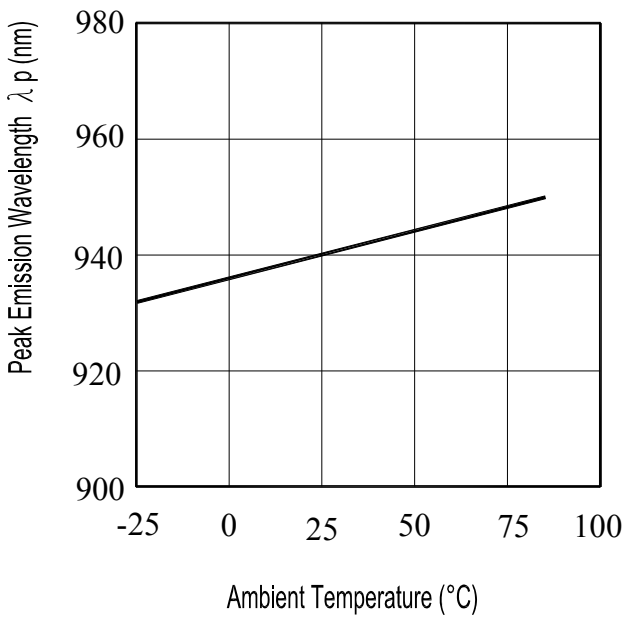


Fig.4 Forward Current vs. Forward Voltage

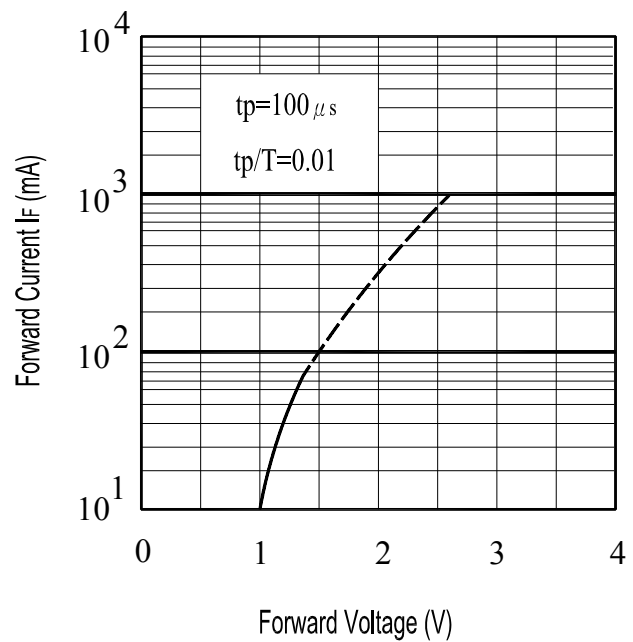


Fig.8 Forward Voltage vs. Ambient Temperature(°C)

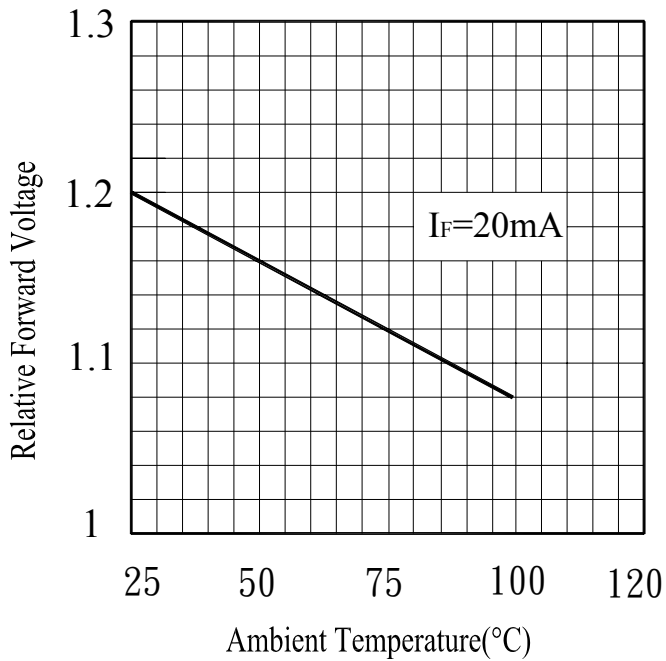
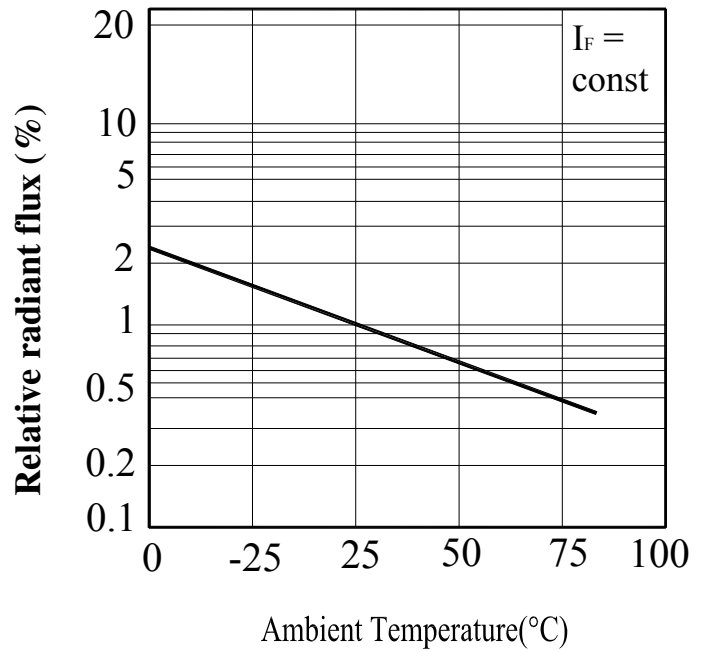


Fig.6 Relative Radiant Flux vs. Ambient Temperature(°C)



Typical Electrical/Optical/Characteristics Curves for PT

Fig.1 Collector Power Dissipation vs. Ambient Temperature

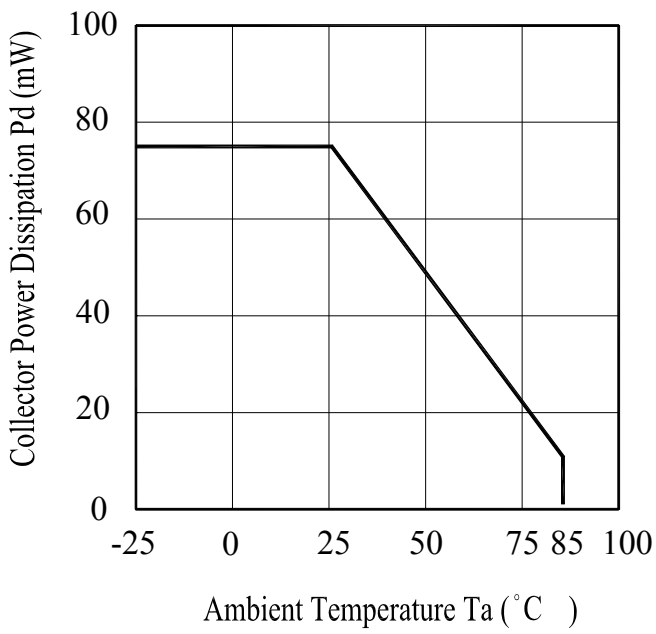


Fig.2 Spectral Sensitivity

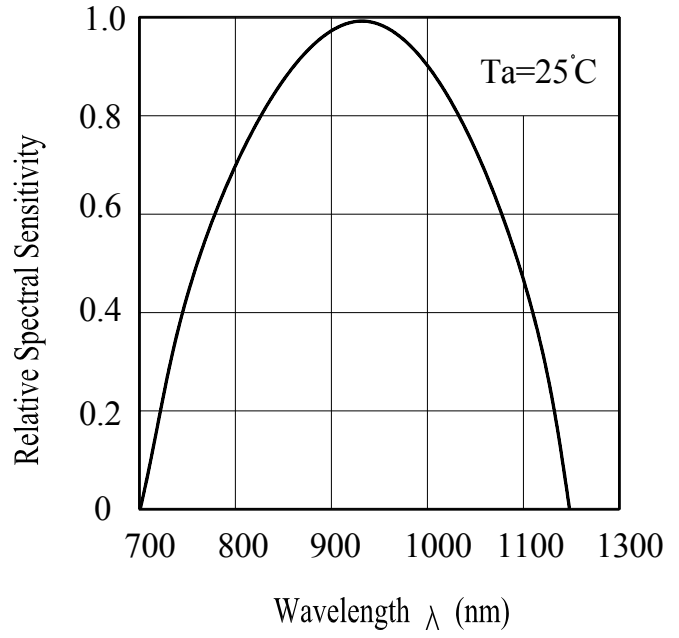


Fig.3 Relative Collector Current vs. Ambient Temperature

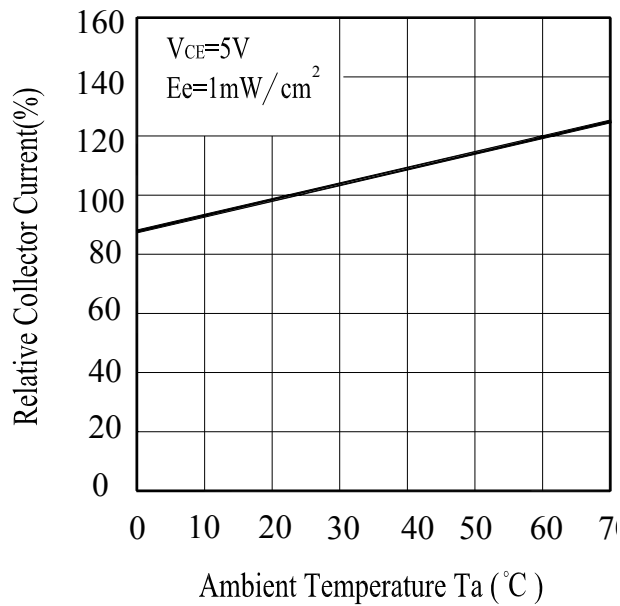
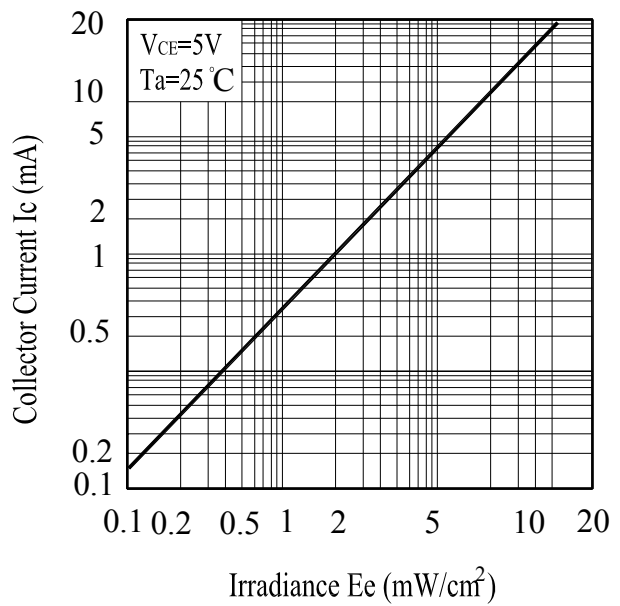


Fig.4 Collector Current vs. Irradiance



Typical Electro-Optical Characteristics Curves

Fig.5 Collector Dark Current vs. Ambient Temperature

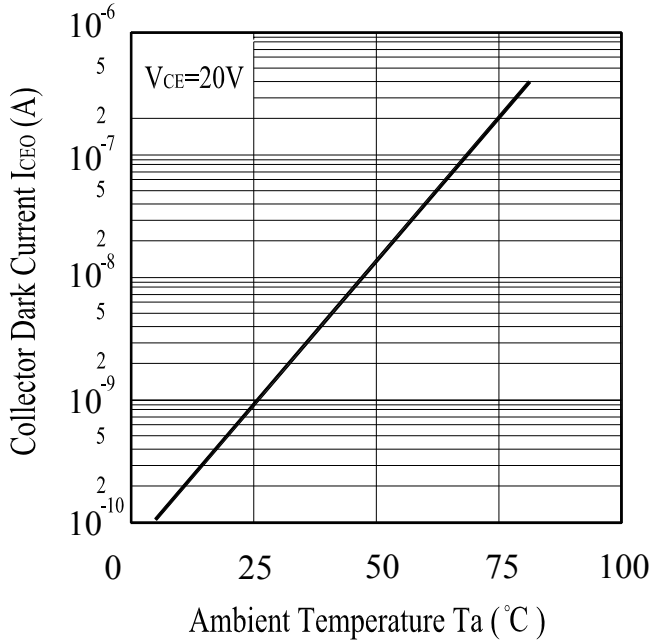
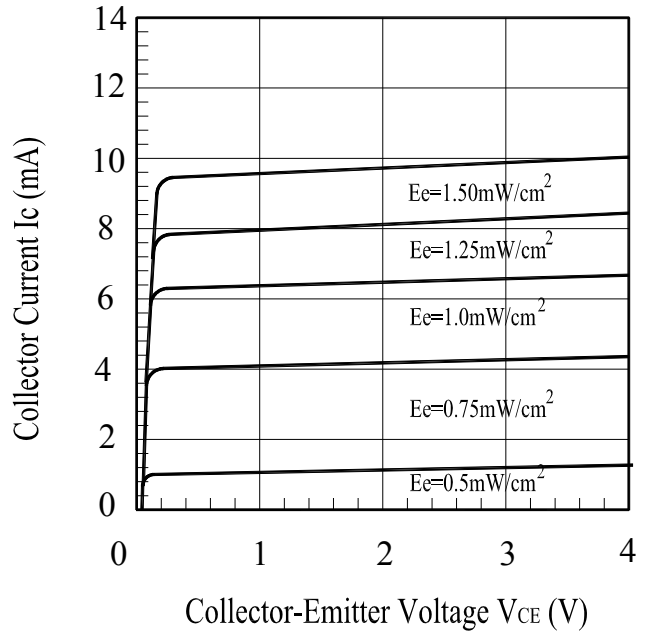


Fig.6 Collector Current vs. Collector-Emitter Voltage



Reliability Test Item And Condition

The reliability of products shall be satisfied with items listed below.

Confidence level : 90%

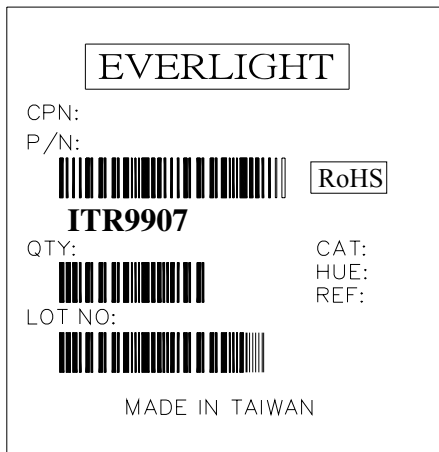
LTPD : 10%

NO.	Item	Test Conditions	Test Hours/ Cycles	Sample Sizes	Failure Judgement Criteria	Ac/Re
1	Solder Resistance	Ta = 260 ±3°C	10 ± 1 sec	22pcs		0/1
2	Temperature Cycle	H : +100°C 15mins ↕ 5mins L : -40°C 15mins	50Cycles	22pcs	IR ≥ U×2 Ee ≤ L×0.8 VF ≥ U×1.2	0/1
3	Thermal Shock	H : +100°C 5mins ↕ 10secs L : -10°C 5mins	50Cycles	22pcs	U : Upper Specification	0/1
4	High Temperature Storage	TEMP. : +100°C	1000hrs	22pcs	Limit L : Lower	0/1
5	Low Temperature Storage	TEMP. : -40°C	1000hrs	22pcs	Specification Limit	0/1
6	DC Operating Life	VCE=5V	1000hrs	22pcs		0/1
7	High Temperature/ High Humidity	85°C / 85% R.H	1000hrs	22pcs		0/1

Packing Quantity Specification

1.100 pcs /1 tube , 30 tubes /1 Box
2.1 Boxes/12 Carton

Label Form Specification



CPN: Customer's Production Number
P/N : Production Number
QTY: Packing Quantity
CAT: Ranks
HUE: Peak Wavelength
REF: Reference
LOT No: Lot Number
MADE IN TAIWAN: Production Place

Notes

1. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
2. When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
3. These specification sheets include materials protected under copyright of EVERLIGHT corporation. Please don't reproduce or cause anyone to reproduce them without EVERLIGHT's consent.

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